

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1-22 (Canceled).

23. (Currently amended) A method of manufacturing a light emitting device comprising:
forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method; and

forming a film comprising an organic material covering said film comprising said inorganic material, ~~by using an ink jet method,~~

wherein said light emitting layer, said second electrode, said film comprising an inorganic material, and said film comprising an organic material are formed continuously using the same film deposition apparatus, and

wherein said light emitting layer and said film comprising an organic material are formed by an ink jet method.

24. (Currently amended) A method of manufacturing a light emitting device comprising:
forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element ~~by using an ink jet method;~~ and

forming a film comprising an inorganic material covering said film comprising said organic material by using a CVD method or an evaporation method,

wherein said light emitting layer, said second electrode, said film comprising an inorganic material, and said film comprising an organic material are formed continuously using the same film deposition apparatus, and

wherein said light emitting layer and said film comprising an organic material are formed by an ink jet method.

25. (Previously presented) A method of manufacturing a light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element; and

forming a film comprising an organic material covering said film comprising said inorganic material,

wherein said light emitting layer and said film comprising an organic material are formed by an ink jet method.

26. (Previously presented) A method of manufacturing a light emitting device comprising:

forming an EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element; and

forming a film comprising an inorganic material covering said film comprising said organic material,

wherein said light emitting layer and said film comprising an organic material are formed by an ink jet method.

27. (Currently amended) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method, and

forming a film comprising an organic material covering said film comprising said inorganic material ~~by an electric field application method, and~~

wherein said light emitting layer and said film comprising an organic material are formed by an electric field application method.

28. (Currently amended) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said EL element ~~by an electric field application method, and~~

forming a film comprising an inorganic material covering said film comprising said organic material by using a CVD method or an evaporation method, and

wherein said light emitting layer and said film comprising an organic material are formed by an electric field application method.

29. (Previously presented) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method, and

forming a film comprising an organic material covering said film comprising said inorganic material by an electric field application method,

wherein the light emitting layer, the second electrode, the film comprising inorganic material, and the film comprising organic material are formed using the same film deposition apparatus.

30. (Previously presented) A method of manufacturing a self-light emitting device comprising:

forming an EL element by an electric field application method, the EL element comprising a first electrode, a light emitting layer over the first electrode, and a second electrode over the light emitting layer;

forming a film comprising an organic material covering said film comprising said inorganic material by an electric field application method; and

forming a film comprising an inorganic material covering said EL element by using a CVD method or an evaporation method,

wherein the light emitting layer, the second electrode, the film comprising inorganic material, and the film comprising organic material are formed using the same film deposition apparatus.

31. (Previously presented) A method of manufacturing a self-light emitting device according to claim 27, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

32. (Previously presented) A method of manufacturing a self-light emitting device according to claim 28, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

33. (Previously presented) A method of manufacturing a self-light emitting device according to claim 29, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

34. (Previously presented) A method of manufacturing a self-light emitting device according to claim 30, wherein the film comprising an inorganic material is formed from silicon nitride, tantalum oxide, aluminum nitride, or carbon.

35. (Previously presented) A method of manufacturing a self-light emitting device according to claim 27, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

36. (Previously presented) A method of manufacturing a self-light emitting device according to claim 28, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

37. (Previously presented) A method of manufacturing a self-light emitting device according to claim 29, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

38. (Previously presented) A method of manufacturing a self-light emitting device according to claim 30, wherein the film comprising an organic material is formed from polyamide, polyimide, acrylic resin, or benzocyclobuten.

39. (Currently amended) A method of manufacturing a self-light emitting device according to claim 27, wherein **[[thee]]** the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type

display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

40. (Currently amended) A method of manufacturing a self-light emitting device according to claim 28, wherein **[[thee]]** the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

41. (Currently amended) A method of manufacturing a self-light emitting device according to claim 29, wherein **[[thee]]** the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.

42. (Currently amended) A method of manufacturing a self-light emitting device according to claim 30, wherein **[[thee]]** the self-light emitting device is incorporated into an electronic appliance selected from the group consisting of a video camera, a head mount type display, an image reproduction apparatus, a portable computer, a personal computer, a portable telephone, and a sound reproduction device.